

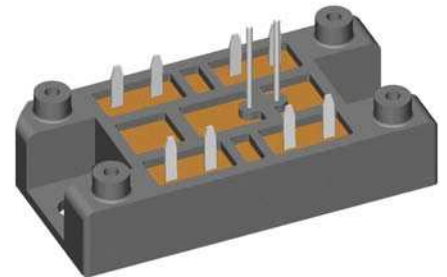
## Standard Rectifier Module

| 3~ Rectifier               | Brake Chopper                  |
|----------------------------|--------------------------------|
| $V_{RRM} = 1600 \text{ V}$ | $V_{CES} = 1200 \text{ V}$     |
| $I_{DAV} = 74 \text{ A}$   | $I_{C25} = 58 \text{ A}$       |
| $I_{FSM} = 550 \text{ A}$  | $V_{CE(sat)} = 1.85 \text{ V}$ |

### 3~ Rectifier Bridge + Brake Unit

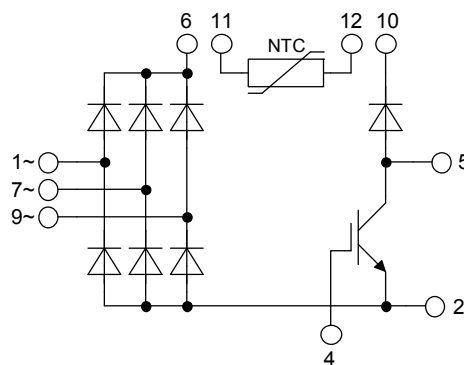
Part number

**VUB72-16NOXT**



Backside: isolated

 E72873



#### Features / Advantages:

- Soldering connections for PCB mounting
- Convenient package outline
- NTC

#### Applications:

- 3~ Rectifier with brake unit for drive inverters

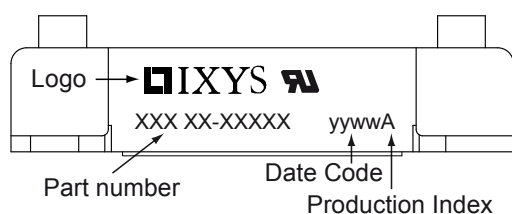
#### Package:

- Housing: V1-A-Pack
- DCB ceramic base plate
- Isolation voltage 4800 V~
- Easy to mount with two screws
- Space and weight savings
- RoHS compliant

| Rectifier  |                                              |                                         |                                | Ratings                        |      |      |                   |
|------------|----------------------------------------------|-----------------------------------------|--------------------------------|--------------------------------|------|------|-------------------|
| Symbol     | Definition                                   | Conditions                              |                                | min.                           | typ. | max. | Unit              |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$           |                                |                                |      | 1700 | V                 |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     | $T_{VJ} = 25^{\circ}\text{C}$           |                                |                                |      | 1600 | V                 |
| $I_R$      | reverse current, drain current               | $V_R = 1600\text{ V}$                   | $T_{VJ} = 25^{\circ}\text{C}$  |                                |      | 20   | $\mu\text{A}$     |
|            |                                              | $V_R = 1600\text{ V}$                   | $T_{VJ} = 125^{\circ}\text{C}$ |                                |      | 3    | mA                |
| $V_F$      | forward voltage drop                         | $I_F = 25\text{ A}$                     | $T_{VJ} = 25^{\circ}\text{C}$  |                                |      | 1.10 | V                 |
|            |                                              | $I_F = 50\text{ A}$                     |                                |                                |      | 1.25 | V                 |
|            |                                              | $I_F = 25\text{ A}$                     | $T_{VJ} = 125^{\circ}\text{C}$ |                                |      | 1.01 | V                 |
|            |                                              | $I_F = 50\text{ A}$                     |                                |                                |      | 1.20 | V                 |
| $I_{DAV}$  | bridge output current                        | $T_C = 80^{\circ}\text{C}$              | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 74   | A                 |
|            |                                              | sine $120^{\circ}$ $d = \frac{1}{3}$    |                                |                                |      |      |                   |
| $V_{FO}$   | threshold voltage                            | } for power loss calculation only       |                                | $T_{VJ} = 150^{\circ}\text{C}$ |      | 0.79 | V                 |
| $r_F$      | slope resistance                             |                                         |                                |                                |      | 7.7  | m $\Omega$        |
| $R_{thJC}$ | thermal resistance junction to case          |                                         |                                |                                |      | 0.90 | K/W               |
| $R_{thCH}$ | thermal resistance case to heatsink          |                                         |                                |                                | 0.30 |      | K/W               |
| $P_{tot}$  | total power dissipation                      | $T_C = 25^{\circ}\text{C}$              |                                |                                |      | 130  | W                 |
| $I_{FSM}$  | max. forward surge current                   | $t = 10\text{ ms; (50 Hz), sine}$       | $T_{VJ} = 45^{\circ}\text{C}$  |                                |      | 550  | A                 |
|            |                                              | $t = 8,3\text{ ms; (60 Hz), sine}$      | $V_R = 0\text{ V}$             |                                |      | 595  | A                 |
|            |                                              | $t = 10\text{ ms; (50 Hz), sine}$       | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 470  | A                 |
|            |                                              | $t = 8,3\text{ ms; (60 Hz), sine}$      | $V_R = 0\text{ V}$             |                                |      | 505  | A                 |
| $I^2t$     | value for fusing                             | $t = 10\text{ ms; (50 Hz), sine}$       | $T_{VJ} = 45^{\circ}\text{C}$  |                                |      | 1.52 | kA <sup>2</sup> s |
|            |                                              | $t = 8,3\text{ ms; (60 Hz), sine}$      | $V_R = 0\text{ V}$             |                                |      | 1.48 | kA <sup>2</sup> s |
|            |                                              | $t = 10\text{ ms; (50 Hz), sine}$       | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 1.11 | kA <sup>2</sup> s |
|            |                                              | $t = 8,3\text{ ms; (60 Hz), sine}$      | $V_R = 0\text{ V}$             |                                |      | 1.06 | kA <sup>2</sup> s |
| $C_J$      | junction capacitance                         | $V_R = 400\text{ V}$ $f = 1\text{ MHz}$ | $T_{VJ} = 25^{\circ}\text{C}$  |                                | 19   |      | pF                |

| Brake IGBT    |                                       |                                                                                                                                                                                                                                                                       |                                | Ratings |      |          |               |
|---------------|---------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------|---------|------|----------|---------------|
| Symbol        | Definition                            | Conditions                                                                                                                                                                                                                                                            |                                | min.    | typ. | max.     | Unit          |
| $V_{CES}$     | collector emitter voltage             | $T_{VJ} = 25^{\circ}\text{C}$                                                                                                                                                                                                                                         |                                |         |      | 1200     | V             |
| $V_{GES}$     | max. DC gate voltage                  |                                                                                                                                                                                                                                                                       |                                |         |      | $\pm 20$ | V             |
| $V_{GEM}$     | max. transient collector gate voltage |                                                                                                                                                                                                                                                                       |                                |         |      | $\pm 30$ | V             |
| $I_{C25}$     | collector current                     | $T_C = 25^{\circ}\text{C}$                                                                                                                                                                                                                                            |                                |         |      | 58       | A             |
| $I_{C80}$     |                                       | $T_C = 80^{\circ}\text{C}$                                                                                                                                                                                                                                            |                                |         |      | 40       | A             |
| $P_{tot}$     | total power dissipation               | $T_C = 25^{\circ}\text{C}$                                                                                                                                                                                                                                            |                                |         |      | 195      | W             |
| $V_{CE(sat)}$ | collector emitter saturation voltage  | $I_C = 35\text{ A}; V_{GE} = 15\text{ V}$                                                                                                                                                                                                                             | $T_{VJ} = 25^{\circ}\text{C}$  |         | 1.85 | 2.15     | V             |
|               |                                       |                                                                                                                                                                                                                                                                       | $T_{VJ} = 125^{\circ}\text{C}$ |         | 2.15 |          | V             |
| $V_{GE(th)}$  | gate emitter threshold voltage        | $I_C = 1.5\text{ mA}; V_{GE} = V_{CE}$                                                                                                                                                                                                                                | $T_{VJ} = 25^{\circ}\text{C}$  | 5.4     | 5.9  | 6.5      | V             |
| $I_{CES}$     | collector emitter leakage current     | $V_{CE} = V_{CES}; V_{GE} = 0\text{ V}$                                                                                                                                                                                                                               | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 0.1      | mA            |
|               |                                       |                                                                                                                                                                                                                                                                       | $T_{VJ} = 125^{\circ}\text{C}$ |         | 0.1  |          | mA            |
| $I_{GES}$     | gate emitter leakage current          | $V_{GE} = \pm 20\text{ V}$                                                                                                                                                                                                                                            |                                |         |      | 500      | nA            |
| $Q_{G(on)}$   | total gate charge                     | $V_{CE} = 600\text{ V}; V_{GE} = 15\text{ V}; I_C = 35\text{ A}$                                                                                                                                                                                                      |                                |         | 110  |          | nC            |
| $t_{d(on)}$   | turn-on delay time                    | <div style="display: flex; align-items: center;"> <div style="font-size: 4em; margin-right: 10px;">}</div> <div> inductive load<br/> <math>V_{CE} = 600\text{ V}; I_C = 35\text{ A}</math><br/> <math>V_{GE} = \pm 15\text{ V}; R_G = 27\ \Omega</math> </div> </div> | $T_{VJ} = 125^{\circ}\text{C}$ |         | 70   |          | ns            |
| $t_r$         | current rise time                     |                                                                                                                                                                                                                                                                       |                                |         | 40   |          | ns            |
| $t_{d(off)}$  | turn-off delay time                   |                                                                                                                                                                                                                                                                       |                                |         | 250  |          | ns            |
| $t_f$         | current fall time                     |                                                                                                                                                                                                                                                                       |                                |         | 100  |          | ns            |
| $E_{on}$      | turn-on energy per pulse              |                                                                                                                                                                                                                                                                       |                                |         | 3.8  |          | mJ            |
| $E_{off}$     | turn-off energy per pulse             |                                                                                                                                                                                                                                                                       |                                |         | 4.1  |          | mJ            |
| RBSOA         | reverse bias safe operating area      | $V_{GE} = \pm 15\text{ V}; R_G = 27\ \Omega$                                                                                                                                                                                                                          | $T_{VJ} = 125^{\circ}\text{C}$ |         |      |          |               |
| $I_{CM}$      |                                       | $V_{CEK} = 1200\text{ V}$                                                                                                                                                                                                                                             |                                |         |      | 105      | A             |
| SCSOA         | short circuit safe operating area     |                                                                                                                                                                                                                                                                       |                                |         |      |          |               |
| $t_{SC}$      | short circuit duration                | $V_{CE} = 900\text{ V}; V_{GE} = \pm 15\text{ V}$                                                                                                                                                                                                                     | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 10       | $\mu\text{s}$ |
| $I_{SC}$      | short circuit current                 | $R_G = 27\ \Omega$ ; non-repetitive                                                                                                                                                                                                                                   |                                |         | 140  |          | A             |
| $R_{thJC}$    | thermal resistance junction to case   |                                                                                                                                                                                                                                                                       |                                |         |      | 0.65     | K/W           |
| $R_{thCH}$    | thermal resistance case to heatsink   |                                                                                                                                                                                                                                                                       |                                |         | 0.25 |          | K/W           |
| Brake Diode   |                                       |                                                                                                                                                                                                                                                                       |                                |         |      |          |               |
| $V_{RRM}$     | max. repetitive reverse voltage       |                                                                                                                                                                                                                                                                       | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 1200     | V             |
| $I_{F25}$     | forward current                       |                                                                                                                                                                                                                                                                       | $T_C = 25^{\circ}\text{C}$     |         |      | 31       | A             |
| $I_{F80}$     |                                       |                                                                                                                                                                                                                                                                       | $T_C = 80^{\circ}\text{C}$     |         |      | 21       | A             |
| $V_F$         | forward voltage                       | $I_F = 25\text{ A}$                                                                                                                                                                                                                                                   | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 2.97     | V             |
|               |                                       |                                                                                                                                                                                                                                                                       | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 2.43     | V             |
| $I_R$         | reverse current                       | $V_R = V_{RRM}$                                                                                                                                                                                                                                                       | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 0.1      | mA            |
|               |                                       |                                                                                                                                                                                                                                                                       | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 0.5      | mA            |
| $Q_{rr}$      | reverse recovery charge               | <div style="display: flex; align-items: center;"> <div style="font-size: 4em; margin-right: 10px;">}</div> <div> <math>V_R = 600\text{ V}</math><br/> <math>-di_F/dt = 400\text{ A}/\mu\text{s}</math><br/> <math>I_F = 25\text{ A}</math> </div> </div>              | $T_{VJ} = 125^{\circ}\text{C}$ |         | 1.2  |          | $\mu\text{C}$ |
| $I_{RM}$      | max. reverse recovery current         |                                                                                                                                                                                                                                                                       |                                |         | 18   |          | A             |
| $t_{rr}$      | reverse recovery time                 |                                                                                                                                                                                                                                                                       |                                |         | 130  |          | ns            |
| $R_{thJC}$    | thermal resistance junction to case   |                                                                                                                                                                                                                                                                       |                                |         |      | 1.6      | K/W           |
| $R_{thCH}$    | thermal resistance case to heatsink   |                                                                                                                                                                                                                                                                       |                                |         | 0.55 |          | K/W           |

| Package V1-A-Pack    |                                                              |                      |                                         | Ratings |      |      |      |
|----------------------|--------------------------------------------------------------|----------------------|-----------------------------------------|---------|------|------|------|
| Symbol               | Definition                                                   | Conditions           |                                         | min.    | typ. | max. | Unit |
| I <sub>RMS</sub>     | RMS current                                                  | per terminal         |                                         |         |      | 100  | A    |
| T <sub>stg</sub>     | storage temperature                                          |                      |                                         | -40     |      | 125  | °C   |
| T <sub>VJ</sub>      | virtual junction temperature                                 |                      |                                         | -40     |      | 150  | °C   |
| Weight               |                                                              |                      |                                         |         | 37   |      | g    |
| M <sub>D</sub>       | mounting torque                                              |                      |                                         | 2       |      | 2.5  | Nm   |
| V <sub>ISOL</sub>    | isolation voltage                                            | t = 1 second         | 50/60 Hz, RMS; I <sub>ISOL</sub> ≤ 1 mA | 4800    |      |      | V    |
|                      |                                                              | t = 1 minute         |                                         | 4000    |      |      | V    |
| d <sub>Spp/App</sub> | creepage distance on surface   striking distance through air | terminal to terminal |                                         | 6.0     |      |      | mm   |
| d <sub>Spb/App</sub> |                                                              | terminal to backside |                                         | 12.0    |      |      | mm   |



| Ordering | Part Number  | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|--------------|--------------------|---------------|----------|----------|
| Standard | VUB72-16NOXT | VUB72-16NOXT       | Box           | 10       | 510741   |

| Similar Part | Package   | Voltage class |
|--------------|-----------|---------------|
| VUB72-12NOXT | V1-A-Pack | 1200          |

### Temperature Sensor NTC

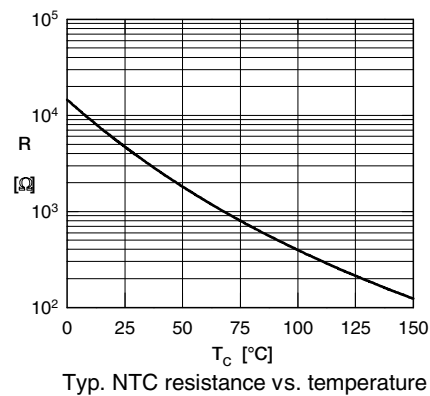
| Symbol      | Definition              | Conditions            | min. | typ. | max. | Unit |
|-------------|-------------------------|-----------------------|------|------|------|------|
| $R_{25}$    | resistance              | $T_{VJ} = 25^{\circ}$ | 2.13 | 2.2  | 2.27 | kΩ   |
| $B_{25/50}$ | temperature coefficient |                       |      | 3560 |      | K    |

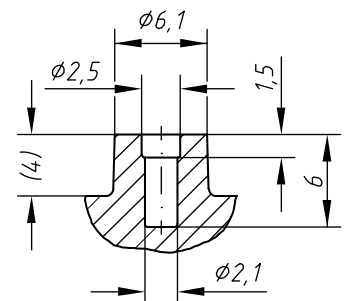
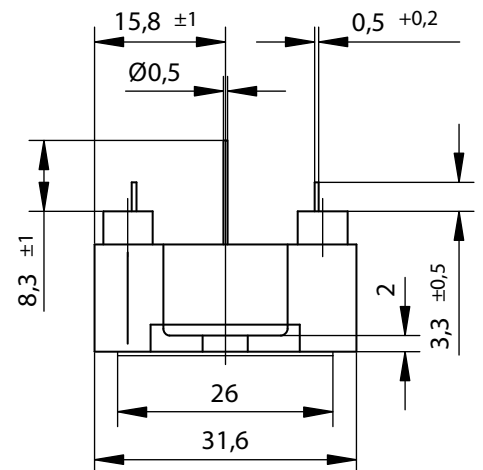
### Equivalent Circuits for Simulation

\* on die level

$T_{VJ} = 150^{\circ}\text{C}$

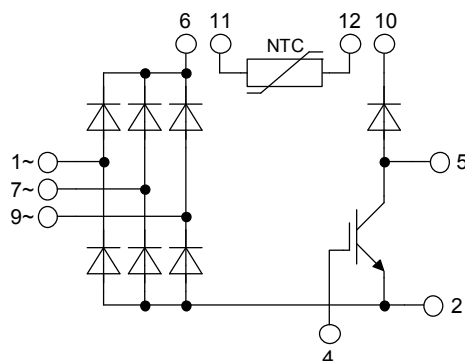
|             |                    | Rectifier | Brake IGBT | Brake Diode |    |
|-------------|--------------------|-----------|------------|-------------|----|
| $V_{0\max}$ | threshold voltage  | 0.79      | 1.1        | 1.16        | V  |
| $R_{0\max}$ | slope resistance * | 6.5       | 40         | 43          | mΩ |





Technical drawing of a mechanical part with dimensions:

- Top horizontal dimension:  $0,5 \pm 0,3$
- Left vertical dimension:  $1,5$
- Right horizontal dimension:  $1 \pm 0,2$
- Bottom horizontal dimension:  $2 \pm 0,2$



## Rectifier

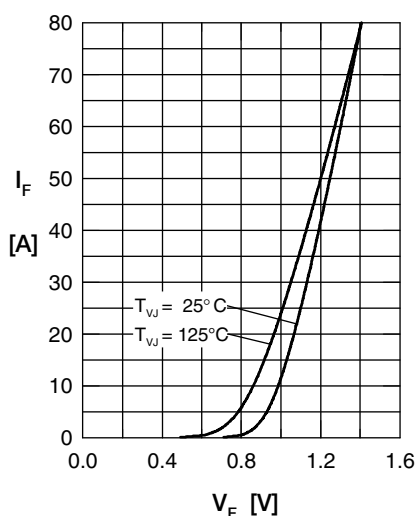


Fig. 1 Typ. forward current vs. voltage drop per diode

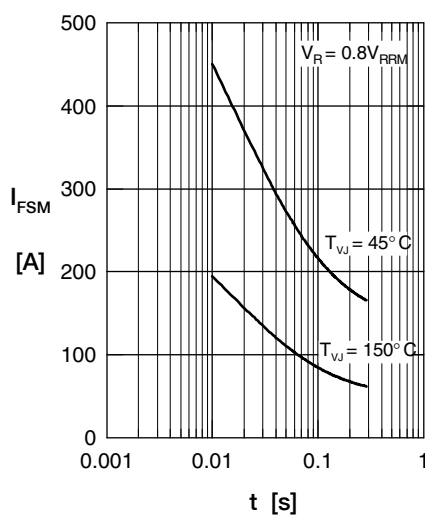


Fig. 2 Surge overload current

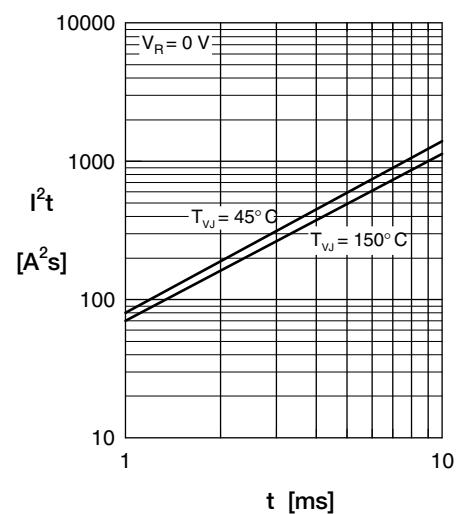


Fig. 3  $I^2t$  versus time per diode

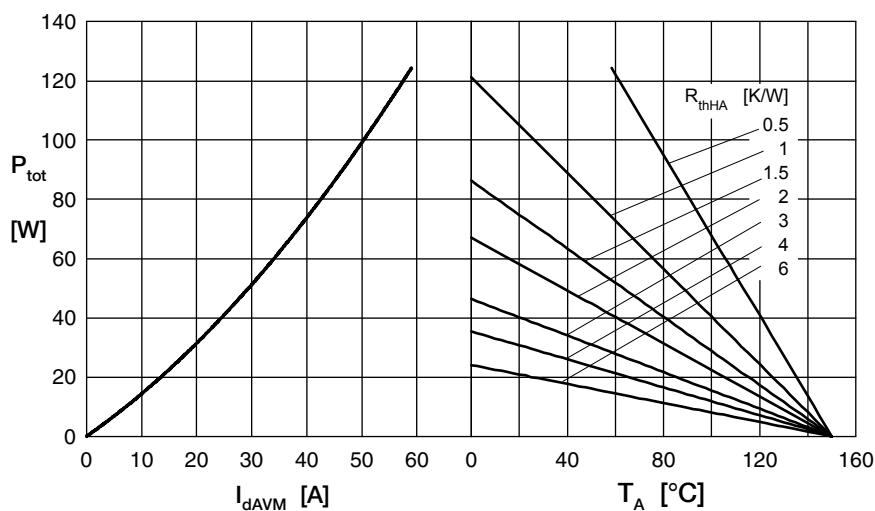


Fig. 4 Power dissipation versus direct output current and ambient temperature, sine 180°

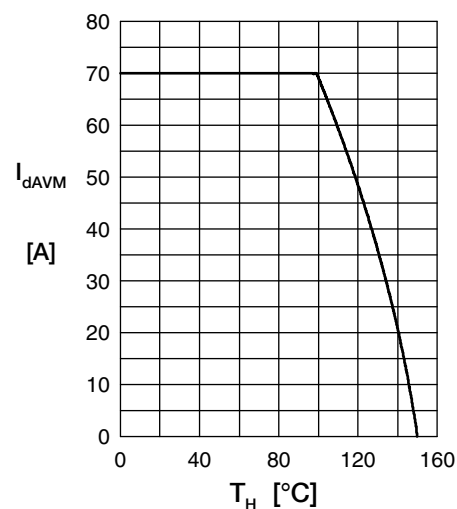


Fig. 5 Max. forward current versus case temperature

## Brake IGBT

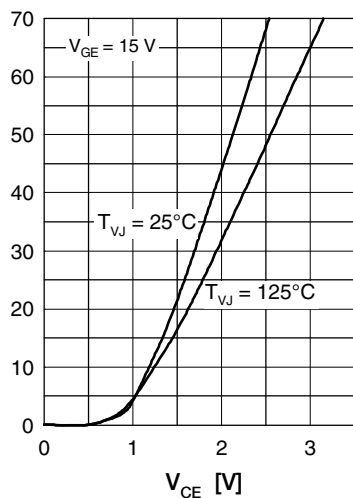


Fig. 1 Typ. output characteristics

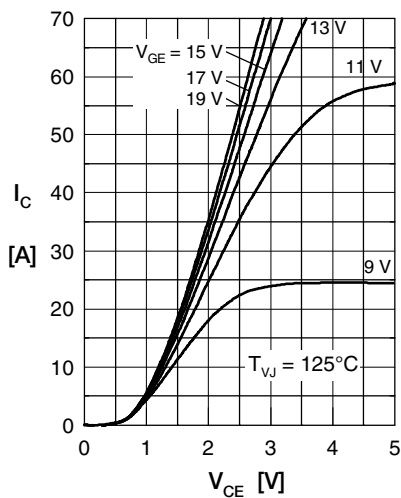


Fig. 2 Typ. output characteristics

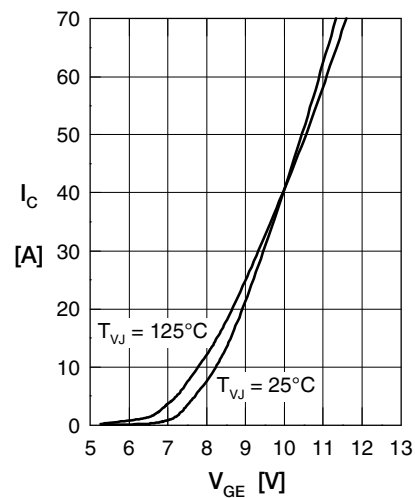


Fig. 3 Typ. transfer characteristics

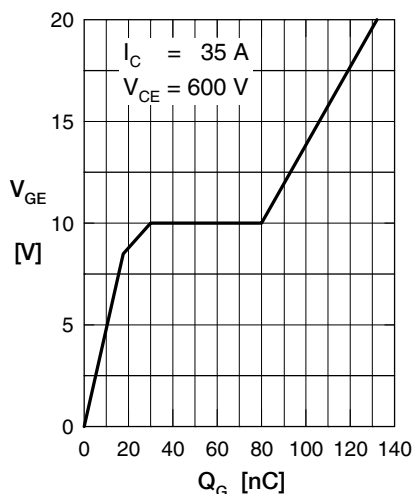


Fig. 4 Typ. turn-on gate charge

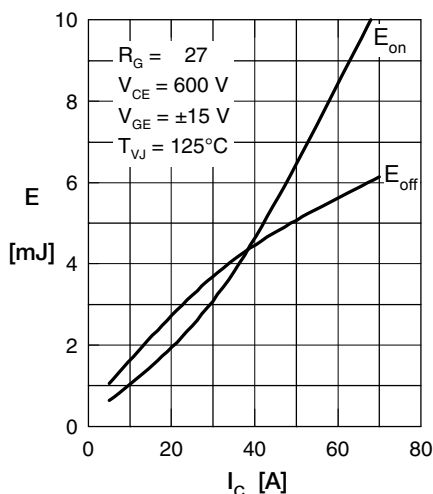


Fig. 5 Typ. switching energy versus collector current

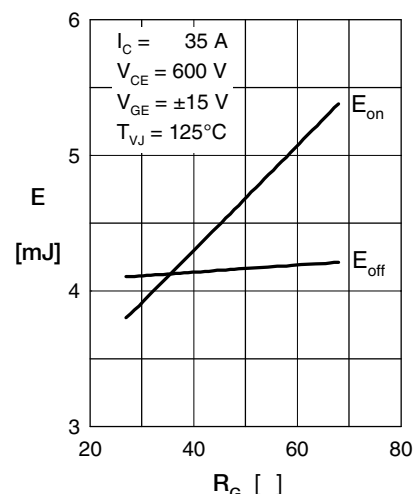


Fig. 6 Typ. switching energy versus gate resistance

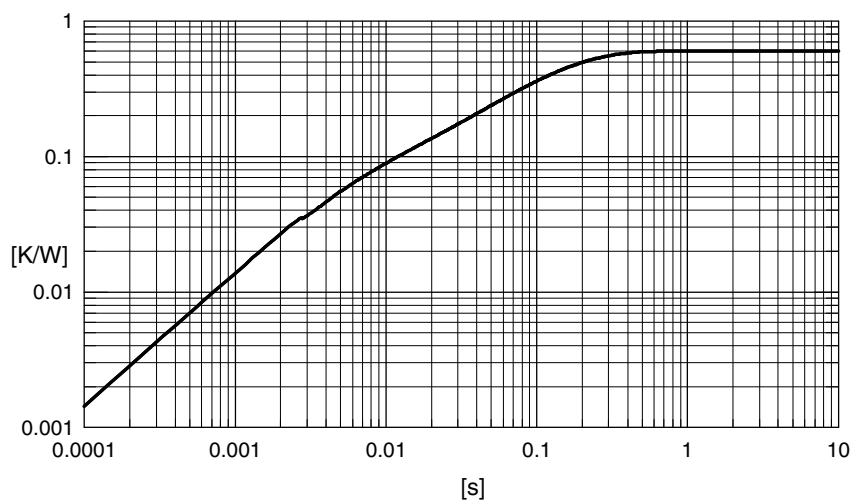


Fig. 7 Typ. transient thermal impedance

## Brake Diode

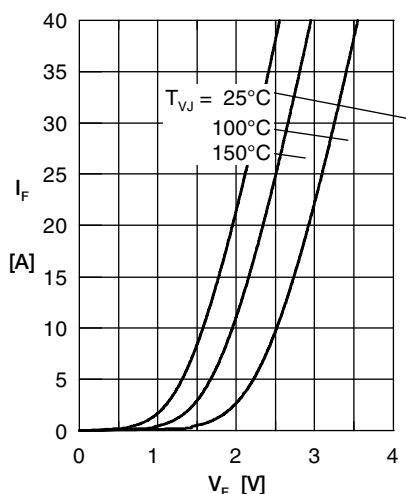


Fig. 1 Forward current  $I_F$  versus  $V_F$

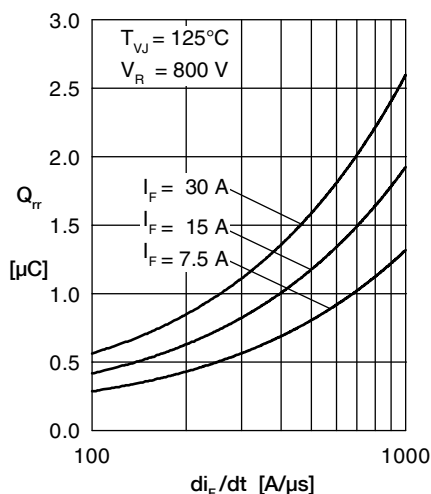


Fig. 2 Typ. reverse recov. charge  $Q_{rr}$  versus  $di_F/dt$

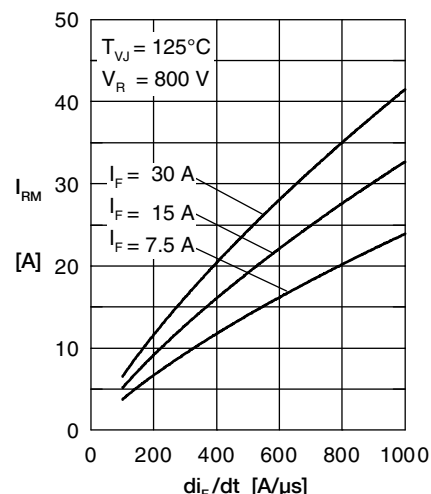


Fig. 3 Typ. peak reverse current  $I_{RM}$  versus  $di_F/dt$

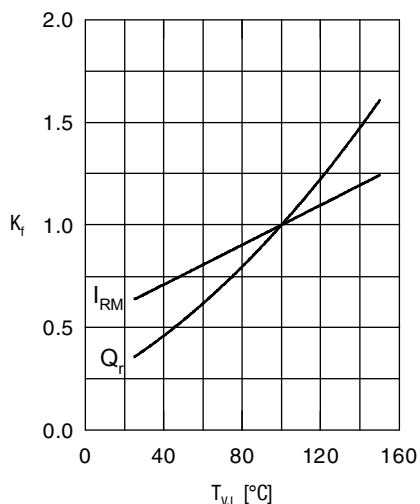


Fig. 4 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$

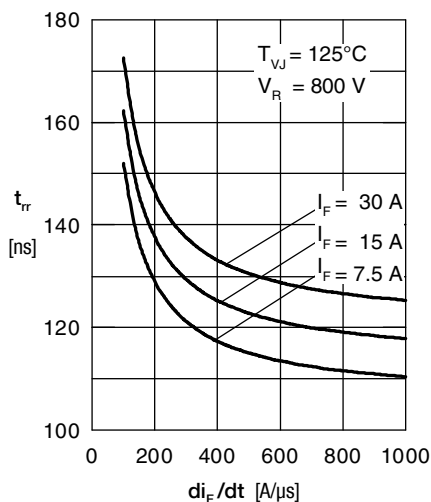


Fig. 5 Typ. recovery time  $t_{rr}$  versus  $di_F/dt$

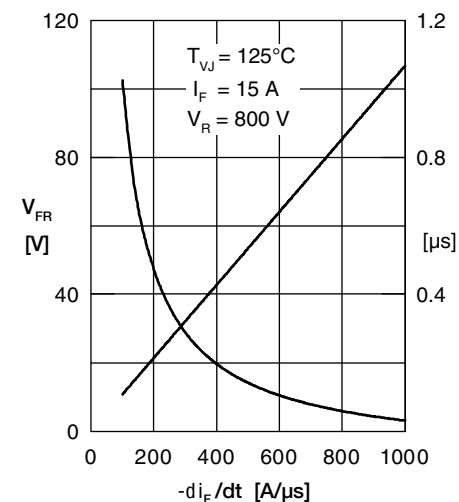


Fig. 6 Typ. peak forward voltage  $V_{FR}$  and  $t_{rr}$  versus  $di_F/dt$

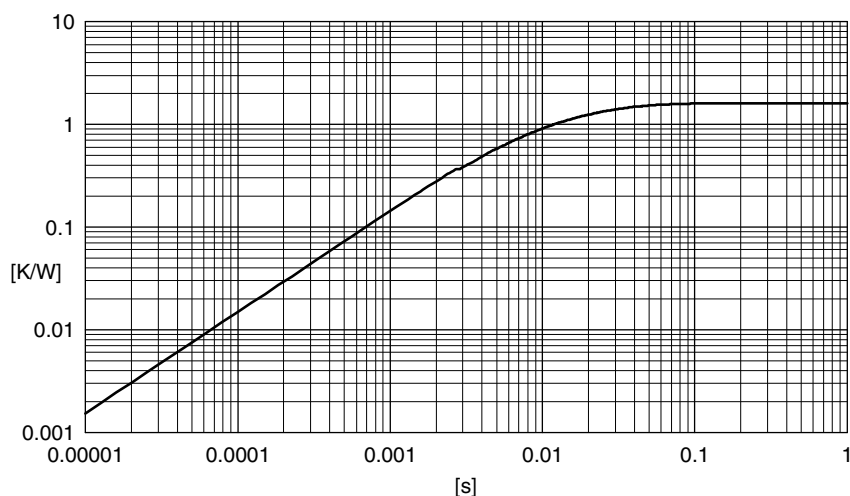


Fig. 7 Transient thermal impedance junction to case